ADS7043 超低功耗、超小尺寸、12 位、1MSPS、SAR ADC

1 特性

- 业界第一款具有毫微瓦功耗的逐次逼近寄存器 (SAR) 模数转换器 (ADC)：
  - 1MSPS 和 1.8V AVDD 时为 243μW
  - 1MSPS 和 3V AVDD 时为 780μW
  - 100kSPS 和 3V AVDD 时为 78μW
  - 1kSPS 和 3V AVDD 时低于 1μW
- 业界最小的 SAR ADC：
  - 采用 X2QFN-8 封装，封装尺寸为 2.25mm^2
- 1MSPS 吞吐量且零延迟
- 宽工作范围：
  - AVDD:1.65V 至 3.6V
  - DVDD：1.65V 至 3.6V（与 AVDD 无关）
  - 温度范围：-40°C 至 125°C
- 出色的性能：
  - 12 位分辨率且无丢码 (NMC)
  - 最大 ±1 最低有效位 (LSB) 的差分非线性 (DNL) 和积分非线性 (INL)
  - 70dB 的信噪比 (SNR)（3V AVDD 时）
  - -80dB 的总谐波失真 (SNR)（3V AVDD 时）
- 单极伪差分输入范围：
  –AVDD/2 至 AVDD/2
- 集成偏移校准
- 串行外设接口 (SPI)™- 兼容串口：16MHz
- 符合 JESD8-7A 标准的数字 I/O

2 应用

- 低功耗数据采集
- 电池供电类手持设备
- 液位传感器
- 超声波流量计
- 电机控制
- 可穿戴健身器
- 便携式医疗设备
- 硬盘
- 血糖仪

3 说明

ADS7043 是一款 1MSPS 模数转换器 (ADC)。该器件支持较宽的模拟输入电压范围（±0.825V 至 ±1.8V），并且包括一个基于电容且内置采样保持电路的逐次逼近寄存器 (SAR) ADC。串行外设接口 (SPI) 兼容串口由 $\overline{CS}$ 和 SCLK 信号控制。输入信号在 $\overline{CS}$ 下降沿进行采样，SCLK 用于转换和串行数据输出。此器件支持宽范围的数字电源（1.65V 至 3.6V），可直接连接到各类主机控制器。此器件符合 JESD8-7A 标准的标称 DVDD 范围（1.65V 至 1.95V）。

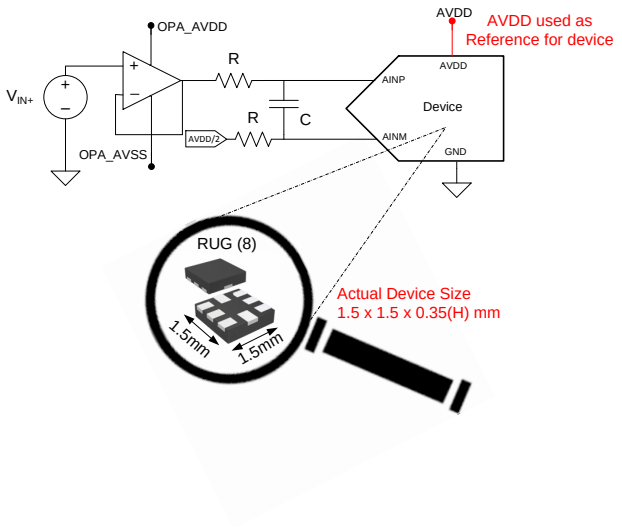
此器件采用 8 引脚微型引线 X2QFN 封装，额定工作温度范围为 –40°C 至 125°C。此器件尺寸微小且功耗极低，非常适合空间受限类电池供电 应用。

器件信息(1)

部件名称	封装	封装尺寸（标称值）
ADS7043	X2QFN (8)	1.50mm x 1.50mm
	超薄小外形尺寸封装 (VSSOP)(8)	2.30mm x 2.00mm

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

典型应用



注：此器件比 0805（2012 公制）SMD 元件小。

目录

4 修订历史记录

Changes from Revision C (February 2015) to Revision D **Page**

- Changed Figure 1 ... 8
- Changed *Serial Interface* section: changed last half of first paragraph, changed Figure 35 ... 19
- Changed Figure 38 ... 22
- 添加了*社区资源*部分 ... 30

Changes from Revision B (December 2014) to Revision C **Page**

- 已更改*宽工作电压范围* 特性 要点：已将 AVDD 的值从 1.8V 改为 1.65V ... 1
- 已将宽模拟输入电压范围下限值改为 ±0.825V （说明 部分第一段） ... 1
- Changed AVDD parameter minimum specification in *Recommended Operating Conditions* table ... 5
- Changed E_O parameter uncalibrated test conditions in *Electrical Characteristics* table ... 6
- Changed *Maximum throughput rate* parameter test conditions in *Electrical Characteristics* table ... 6
- Changed *AVDD* parameter minimum specification in *Electrical Characteristics* table ... 7
- Changed conditions for *Timing Characteristics* table: changed range of AVDD and added C_{LOAD} condition ... 7
- Changed t_{D_CKDO} specification in *Timing Characteristics* table ... 7
- Added f_{SCLK} minimum specification to *Timing Characteristics* table ... 7
- Changed titles of Figure 26 to Figure 30 ... 12
- Changed *Reference* sub-section in *Feature Description* section ... 16
- Changed AVDD range in description of $f_{CLK-CAL}$ parameter in Table 2 ... 21
- Changed AVDD range in description of $f_{CLK-CAL}$ parameter in Table 3 ... 22
- Changed *Reference Circuit* section in *Application Information* ... 25
- Added last two sentences to *AVDD and DVDD Supply Recommendations* section ... 28

Changes from Revision A (November 2014) to Revision B **Page**

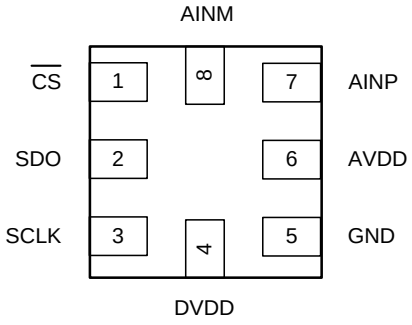
- Changed ESD Ratings table to latest standards 5
- Added footnotes to *Electrical Characteristics* table 6
- Changed y-axis unit in Figure 30 13

Changes from Original (November 2014) to Revision A **Page**

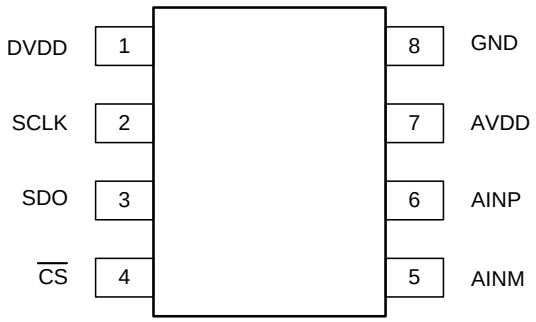
- 已更改产品预览数据表..... 1

5 Pin Configuration and Functions

RUG Package
8-Pin X2QFN
Top View



DCU Package
8-Pin Leaded VSSOP
Top View



Pin Functions

PIN			I/O	DESCRIPTION
NAME	NO. RUG	NO. DCU		
AINM	8	5	Analog input	Analog signal input, negative
AINP	7	6	Analog input	Analog signal input, positive
AVDD	6	7	Supply	Analog power-supply input, also provides the reference voltage to the ADC
$\overline{CS}$	1	4	Digital input	Chip-select signal, active low
DVDD	4	1	Supply	Digital I/O supply voltage
GND	5	8	Supply	Ground for power supply, all analog and digital signals are referred to this pin
SCLK	3	2	Digital input	Serial clock
SDO	2	3	Digital output	Serial data out

6 Specifications

6.1 Absolute Maximum Ratings(1)

	MIN	MAX	UNIT
AVDD to GND	–0.3	3.9	V
DVDD to GND	–0.3	3.9	V
AINP to GND	–0.3	AVDD + 0.3	V
AINM to GND	–0.3	AVDD + 0.3	V
Digital input voltage to GND	–0.3	DVDD + 0.3	V
Storage temperature, T_{stg}	–60	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101(2)	±1000	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
AVDD	Analog supply voltage range	1.65	3.6	V
DVDD	Digital supply voltage range	1.65	3.6	V
T_A	Operating free-air temperature	–40	125	°C

6.4 Thermal Information

THERMAL METRIC(1)		ADS7043		UNIT
		RUG (X2QFN)	DCU (VSSOP)	
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	177.5	235.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	51.5	79.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	76.7	117.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	1.0	8.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	76.7	116.5	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, SPRA953.

6.5 Electrical Characteristics

At T_A = –40°C to 125°C, AVDD = 3 V, DVDD = 1.65 V to 3.6 V, f_{SAMPLE} = 1 MSPS, unless otherwise noted.

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT
ANALOG INPUT							
	Full-scale input voltage span(1)			–AVDD / 2		AVDD / 2	V
	Absolute input voltage range	AINP to GND		–0.1		AVDD + 0.1	V
		AINM to GND		AVDD / 2–0.1		AVDD / 2 + 0.1	
C_S	Sampling capacitance				15		pF
SYSTEM PERFORMANCE							
	Resolution				12		Bits
NMC	No missing codes			12			Bits
INL	Integral nonlinearity		AVDD = 3 V	–1	±0.7	1	LSB(2)
			AVDD = 1.8 V	–2	±1	2	
DNL	Differential nonlinearity		AVDD = 3 V	–0.99	±0.5	1	LSB
			AVDD = 1.8 V	–0.99	±0.7	2	
E_O	Uncalibrated offset error		AVDD = 1.65 V to 3.6 V		±12		LSB
	Calibrated offset error(3)		AVDD = 3 V	–3	±0.5	3	
			AVDD = 1.8 V	–4	±1	4	
dV_{OS}/dT	Offset error drift with temperature				5		ppm/°C
E_G	Gain error		AVDD = 3 V	–0.1	±0.05	0.1	%FS
			AVDD = 1.8 V	–0.2	±0.1	0.2	
	Gain error drift with temperature				2		ppm/°C
SAMPLING DYNAMICS							
t_{ACQ}	Acquisition time			200			ns
	Maximum throughput rate		16-MHz SCLK, AVDD = 1.65 V to 3.6 V			1	MHz
DYNAMIC CHARACTERISTICS							
SNR	Signal-to-noise ratio(4)		f_{IN} = 2 kHz, AVDD = 3 V	69	70		dB
			f_{IN} = 2 kHz, AVDD = 1.8 V		68		
THD	Total harmonic distortion(4)(5)		f_{IN} = 2 kHz, AVDD = 3 V		–80		dB
SINAD	Signal-to-noise and distortion(4)		f_{IN} = 2 kHz, AVDD = 3 V	68	69.5		dB
			f_{IN} = 2 kHz, AVDD = 1.8 V		67.5		
SFDR	Spurious-free dynamic range(4)		f_{IN} = 2 kHz, AVDD = 3 V		85		dB
$BW_{(fp)}$	Full-power bandwidth		At –3 dB, AVDD = 3 V		25		MHz
DIGITAL INPUT/OUTPUT (CMOS Logic Family)							
V_{IH}	High-level input voltage(6)			0.65 DVDD		DVDD + 0.3	V
V_{IL}	Low-level input voltage(6)			–0.3		0.35 DVDD	V
V_{OH}	High-level output voltage(6)		At I_{source} = 500 µA	0.8 DVDD		DVDD	V
			At I_{source} = 2 mA	DVDD – 0.45		DVDD	
V_{OL}	Low-level output voltage(6)		At I_{sink} = 500 µA	0		0.2 DVDD	V
			At I_{sink} = 2 mA	0		0.45	

(1) Ideal input span; does not include gain or offset error.
(2) LSB means least significant bit.
(3) Refer to the *Offset Calibration* section for more details.
(4) All specifications expressed in decibels (dB) refer to the full-scale input (FSR) and are tested with an input signal 0.5 dB below full-scale, unless otherwise specified.
(5) Calculated on the first nine harmonics of the input frequency.
(6) Digital voltage levels comply with the JESD8-7A standard for DVDD from 1.65 V to 1.95 V. See the *Digital Voltage Levels* section for more details.

Electrical Characteristics (continued)

At T_A = –40°C to 125°C, AVDD = 3 V, DVDD = 1.65 V to 3.6 V, f_{SAMPLE} = 1 MSPS, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER-SUPPLY REQUIREMENTS						
AVDD	Analog supply voltage		1.65	3	3.6	V
DVDD	Digital I/O supply voltage		1.65	3	3.6	V
I_{AVDD}	Analog supply current	At 1 MSPS with AVDD = 3 V			260	µA
		At 100 kSPS with AVDD = 3 V			26	
		At 1 MSPS with AVDD = 1.8 V		135		
P_D	Power dissipation	At 1 MSPS with AVDD = 3 V			780	µW
		At 100 kSPS with AVDD = 3 V			78	
		At 1 MSPS with AVDD = 1.8 V		243		

6.6 Timing Characteristics

All specifications are at T_A = –40°C to 125°C, AVDD = 1.65 V to 3.6 V, DVDD = 1.65 V to 3.6 V, and C_{LOAD} on SDO = 20 pF, unless otherwise specified.

		MIN	TYP	MAX	UNIT
TIMING SPECIFICATIONS					
$f_{THROUGHPUT}$	Throughput			1	MSPS
t_{CYCLE}	Cycle time	1			µs
t_{CONV}	Conversion time			$12.5 \times t_{SCLK} + t_{SU\_CSCK}$	ns
t_{DV_CSDO}	Delay time: $\overline{CS}$ falling to data enable			10	ns
t_{D_CKDO}	Delay time: SCLK falling to (next) data valid on DOUT, AVDD = 1.8 V to 3.6 V			30	ns
	Delay time: SCLK falling to (next) data valid on DOUT, AVDD = 1.65 V to 1.8 V			50	
t_{DZ_CSDO}	Delay time: $\overline{CS}$ rising to DOUT going to 3-state	5			ns
TIMING REQUIREMENTS					
t_{ACQ}	Acquisition time	200			ns
f_{SCLK}	SCLK frequency	0.016		16	MHz
t_{SCLK}	SCLK period	62.5			ns
t_{PH_CK}	SCLK high time	0.45		0.55	t_{SCLK}
t_{PL_CK}	SCLK low time	0.45		0.55	t_{SCLK}
t_{PH_CS}	$\overline{CS}$ high time	60			ns
t_{SU_CSCK}	Setup time: $\overline{CS}$ falling to SCLK falling	15			ns
t_{D_CKCS}	Delay time: last SCLK falling to $\overline{CS}$ rising	10			ns

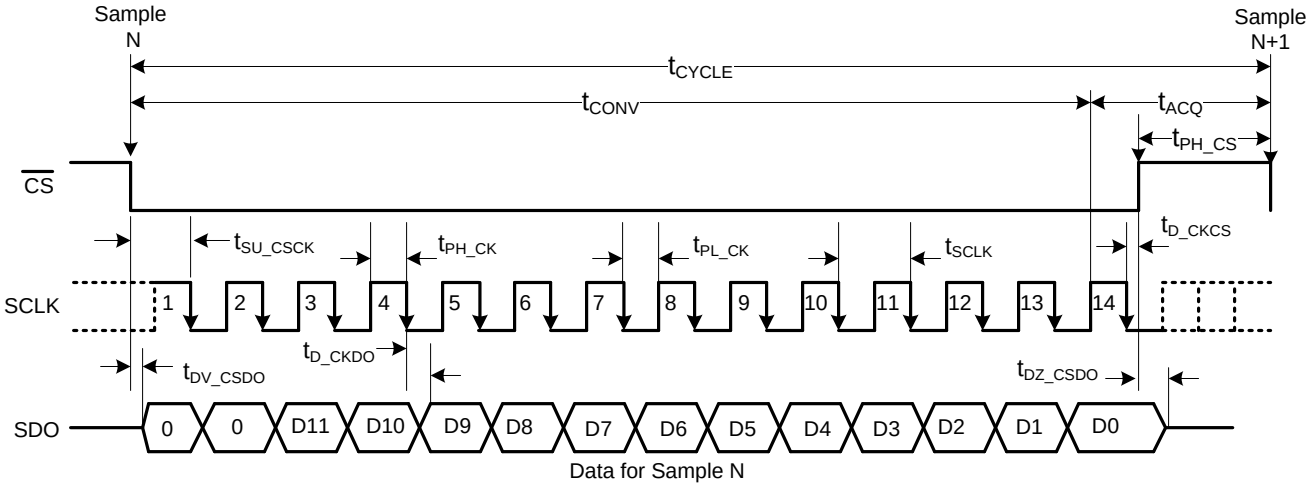
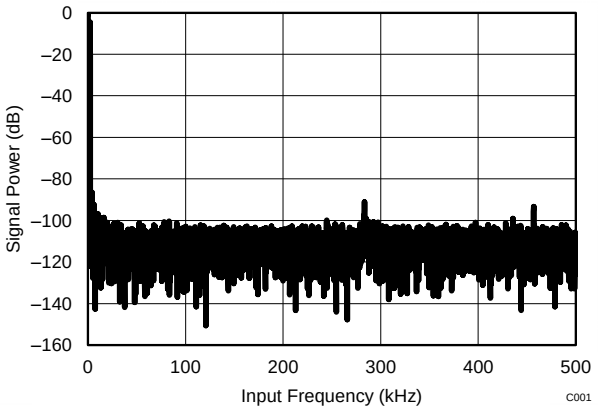


Figure 1. Timing Diagram

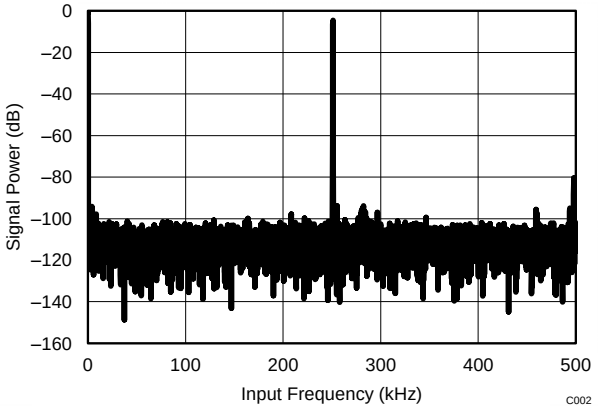
6.7 Typical Characteristics

At T_A = 25°C, AVDD = 3 V, DVDD = 1.8 V, and f_{SAMPLE} = 1 MSPS, unless otherwise noted.



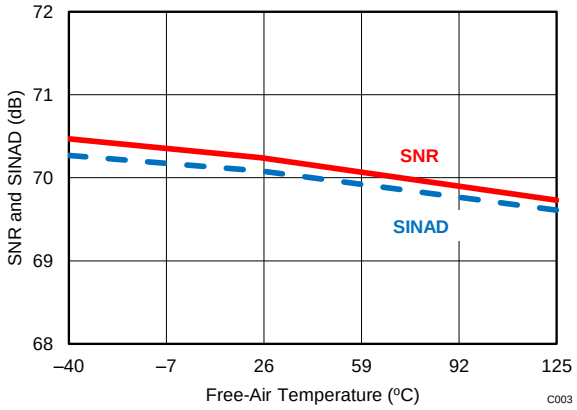
SNR = 70.25 dB THD = –80.3 dB f_{IN} = 2 kHz
Number of samples = 8192

Figure 2. Typical FFT



SNR = 69.7 dB THD = –75.5 dB f_{IN} = 250 kHz
Number of samples = 8192

Figure 3. Typical FFT



f_{IN} = 2 kHz

Figure 4. SNR and SINAD vs Temperature

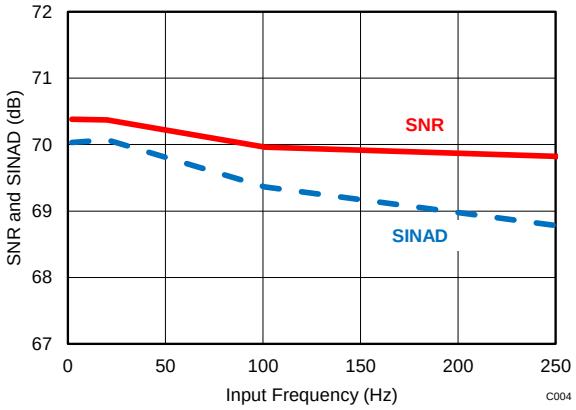


Figure 5. SNR and SINAD vs Input Frequency

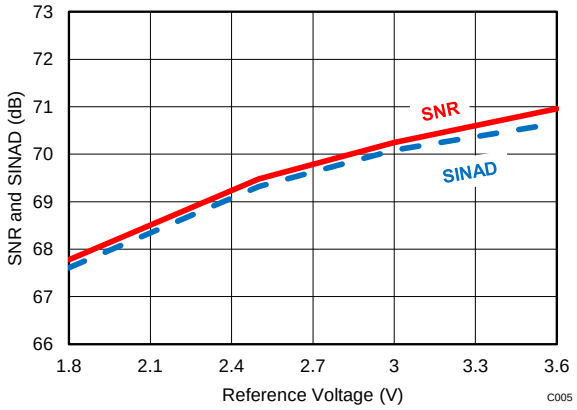


Figure 6. SNR and SINAD vs Reference Voltage (AVDD)

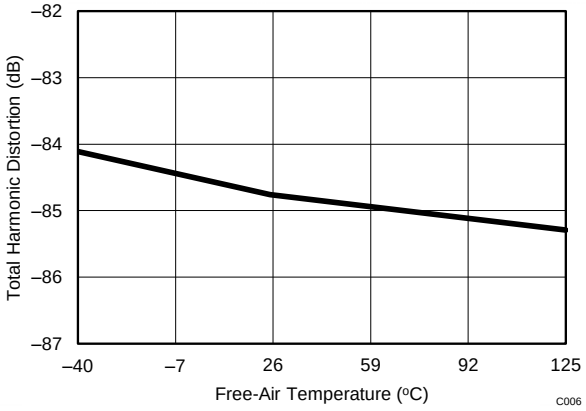


Figure 7. THD vs Free-Air Temperature

Typical Characteristics (continued)

At T_A = 25°C, AVDD = 3 V, DVDD = 1.8 V, and f_{SAMPLE} = 1 MSPS, unless otherwise noted.

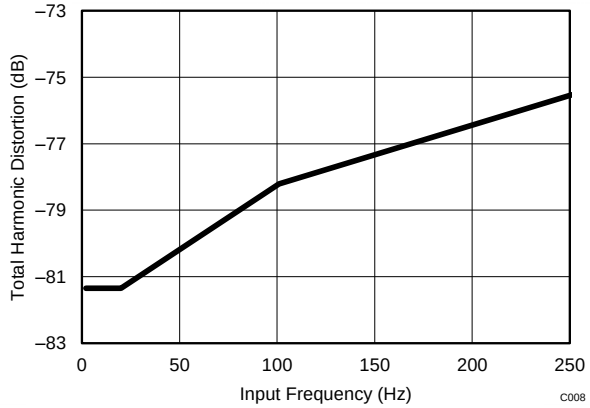


Figure 8. THD vs Input Frequency

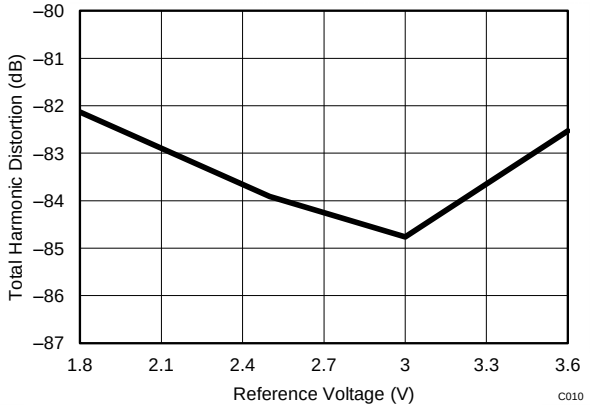


Figure 9. THD vs Reference Voltage (AVDD)

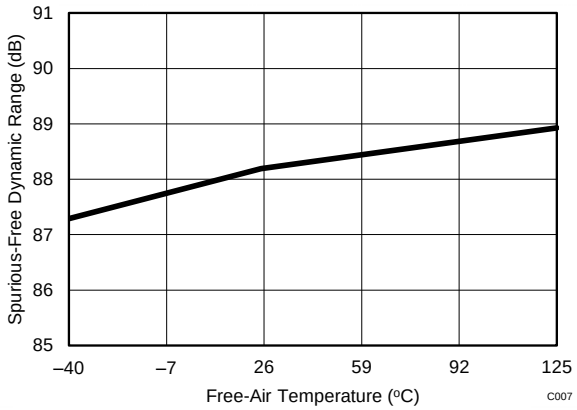


Figure 10. SFDR vs Free-Air Temperature

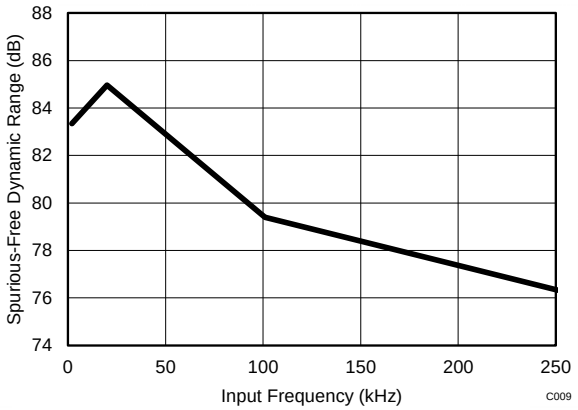


Figure 11. SFDR vs Input Frequency

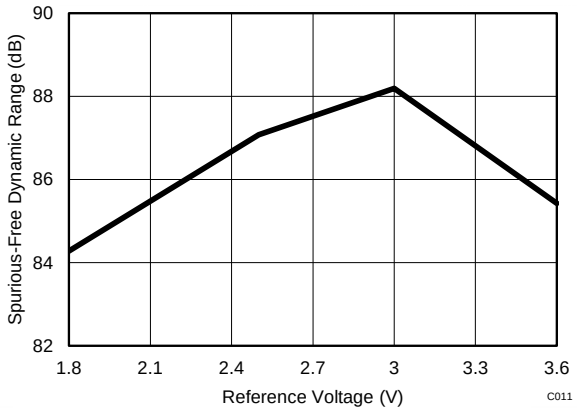
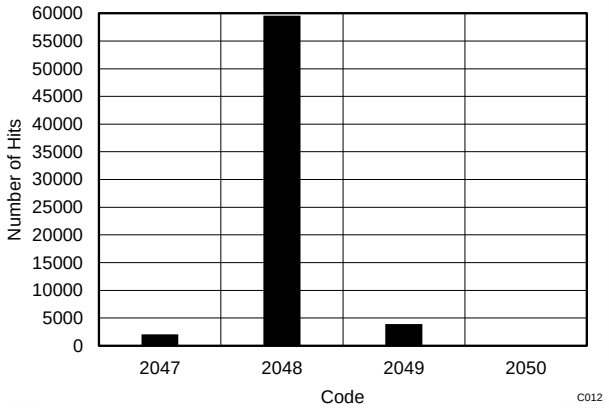


Figure 12. SFDR vs Reference Voltage (AVDD)



Mean code = 2048.03 Sigma = 0.3

Figure 13. DC Input Histogram

Typical Characteristics (continued)

At T_A = 25°C, AVDD = 3 V, DVDD = 1.8 V, and f_{SAMPLE} = 1 MSPS, unless otherwise noted.

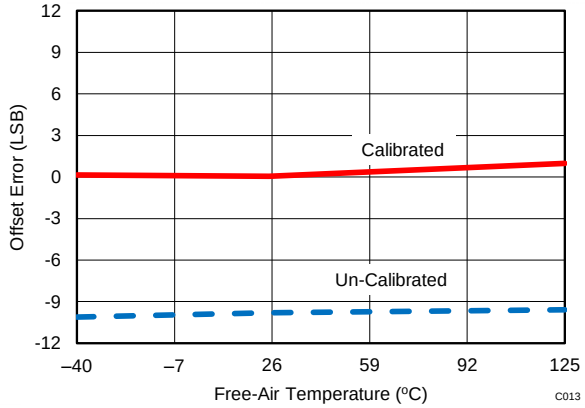


Figure 14. Offset vs Free-Air Temperature

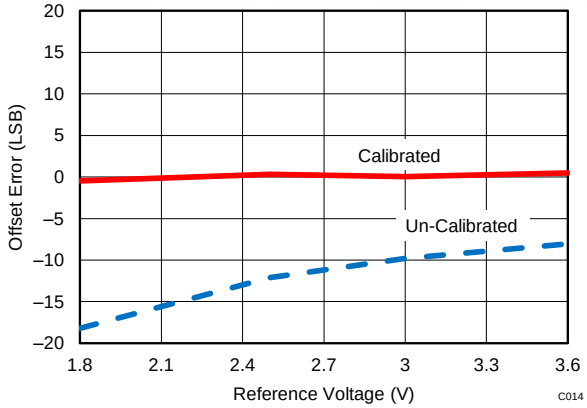


Figure 15. Offset vs Reference Voltage (AVDD)

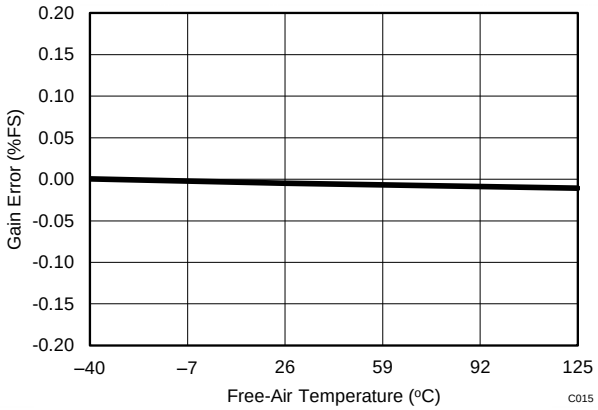


Figure 16. Gain Error vs Free-Air Temperature

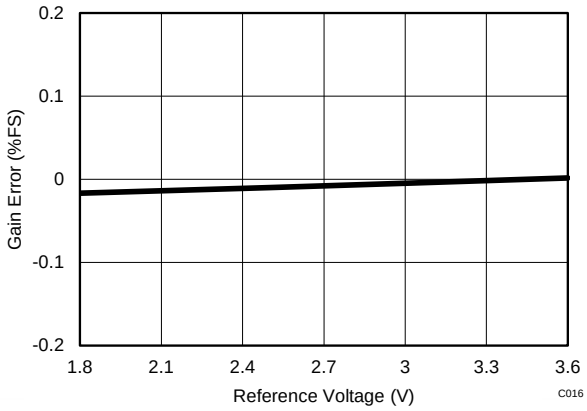


Figure 17. Gain Error vs Reference Voltage (AVDD)

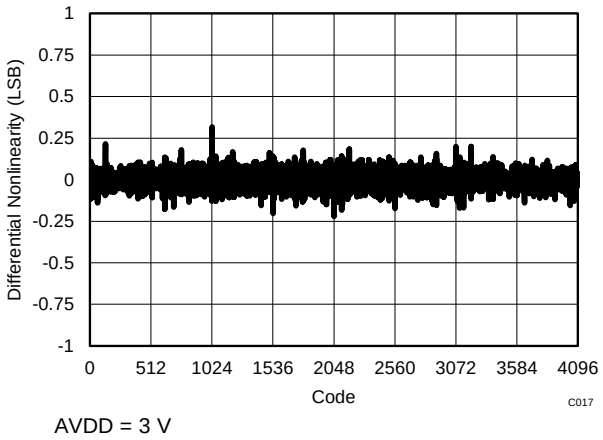


Figure 18. Typical DNL

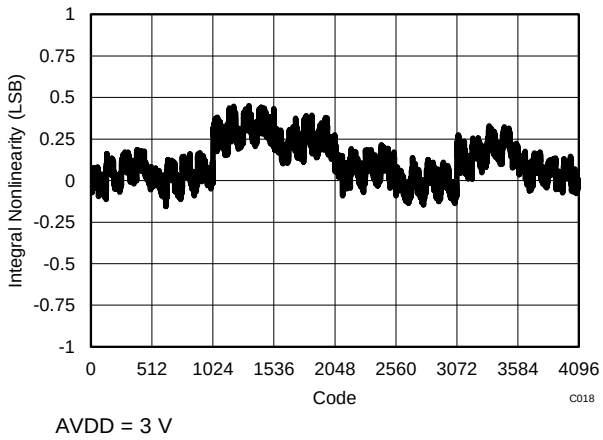
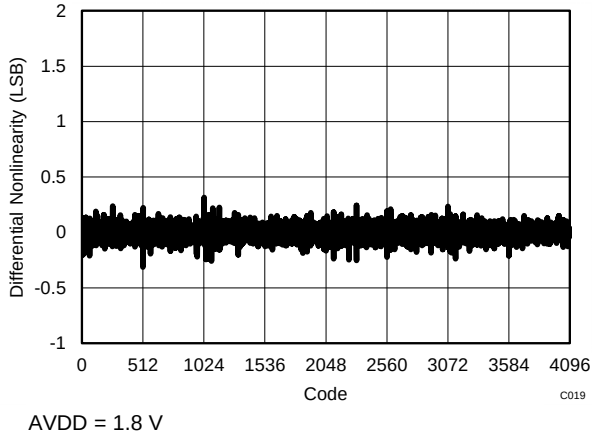


Figure 19. Typical INL

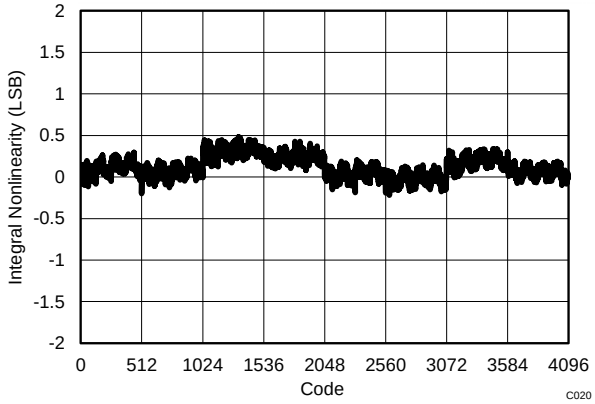
Typical Characteristics (continued)

At T_A = 25°C, AVDD = 3 V, DVDD = 1.8 V, and f_{SAMPLE} = 1 MSPS, unless otherwise noted.



AVDD = 1.8 V

Figure 20. Typical DNL



AVDD = 1.8 V

Figure 21. Typical INL

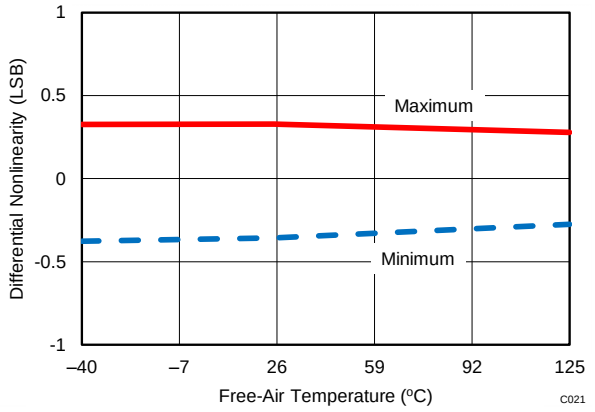


Figure 22. DNL vs Free-Air-Temperature

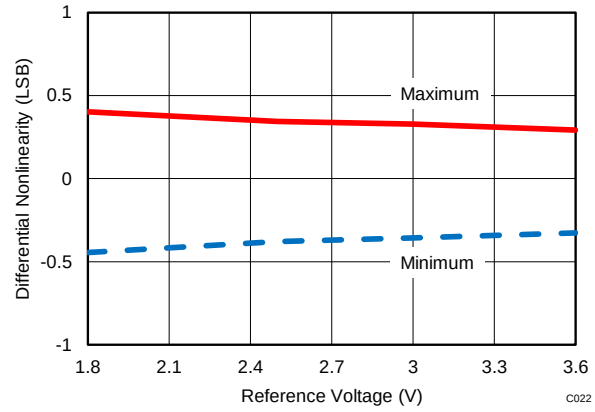


Figure 23. DNL vs Reference Voltage (AVDD)

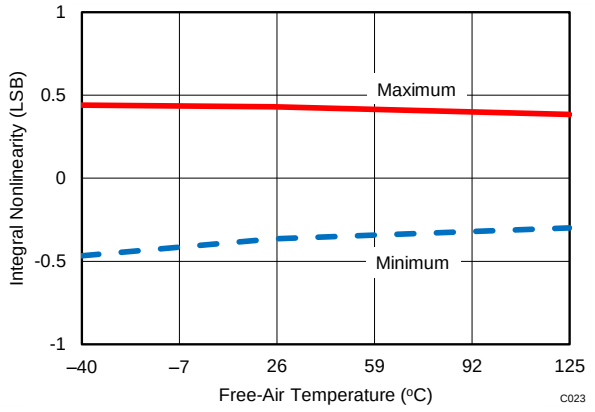


Figure 24. INL vs Free-Air-Temperature

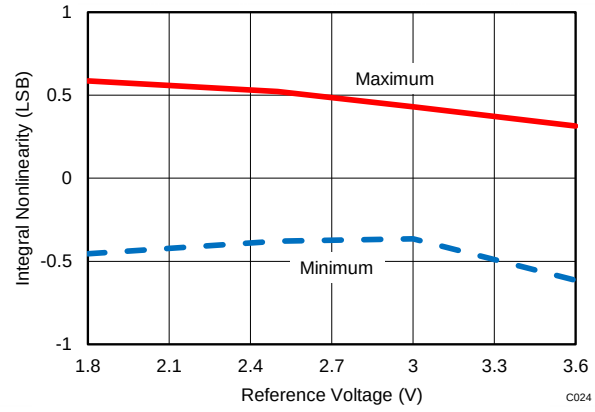
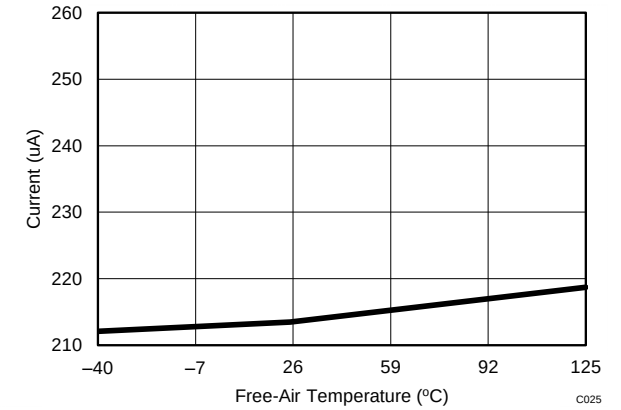


Figure 25. INL vs Reference Voltage (AVDD)

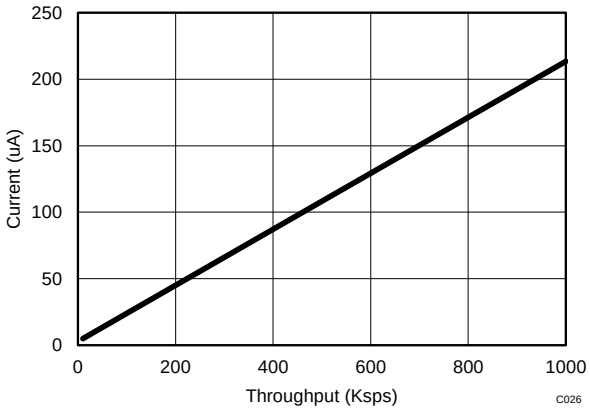
Typical Characteristics (continued)

At T_A = 25°C, AVDD = 3 V, DVDD = 1.8 V, and f_{SAMPLE} = 1 MSPS, unless otherwise noted.



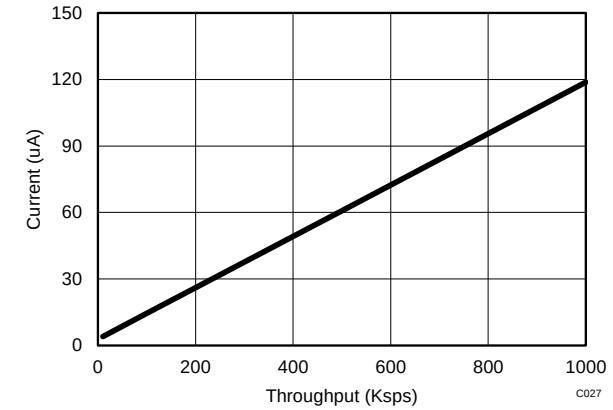
f_{SAMPLE} = 1 MSPS

Figure 26. AVDD Supply Current vs Free-Air Temperature



AVDD = 3 V

Figure 27. AVDD Supply Current vs Throughput



AVDD = 1.8 V

Figure 28. AVDD Supply Current vs Throughput

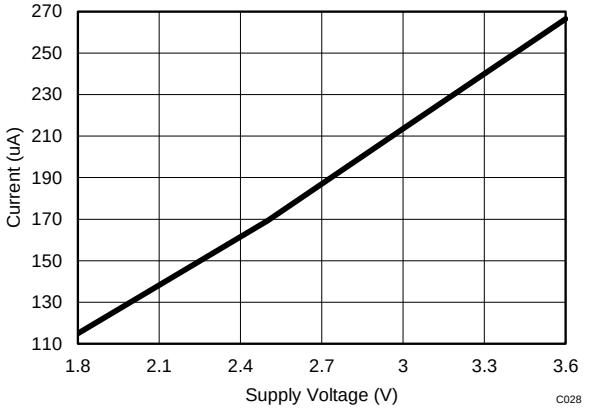


Figure 29. AVDD Supply Current vs AVDD Voltage

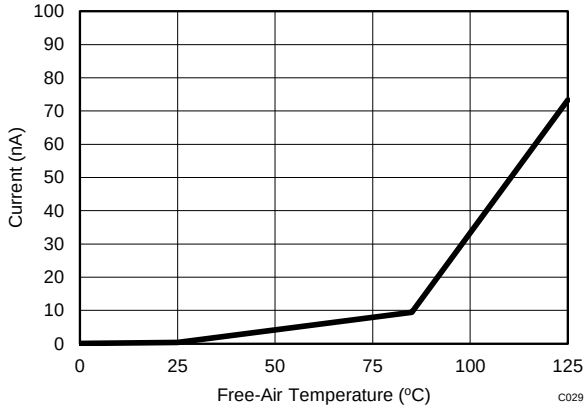


Figure 30. AVDD Static Current vs Free-Air Temperature

7 Parameter Measurement Information

7.1 Digital Voltage Levels

The device complies with the JESD8-7A standard for DVDD from 1.65 V to 1.95 V. Figure 31 shows voltage levels for the digital input and output pins.

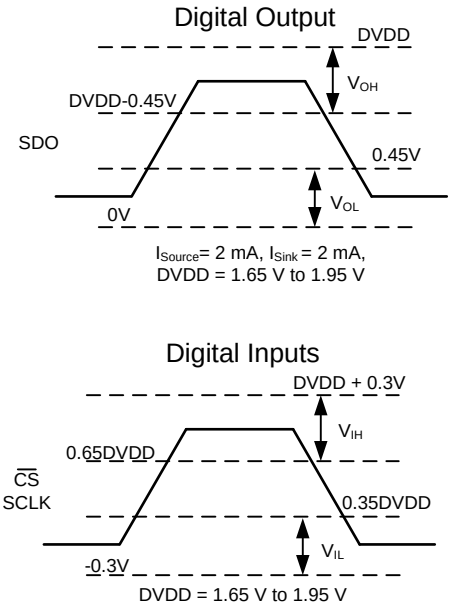


Figure 31. Digital Voltage Levels as per the JESD8-7A Standard

8 Detailed Description

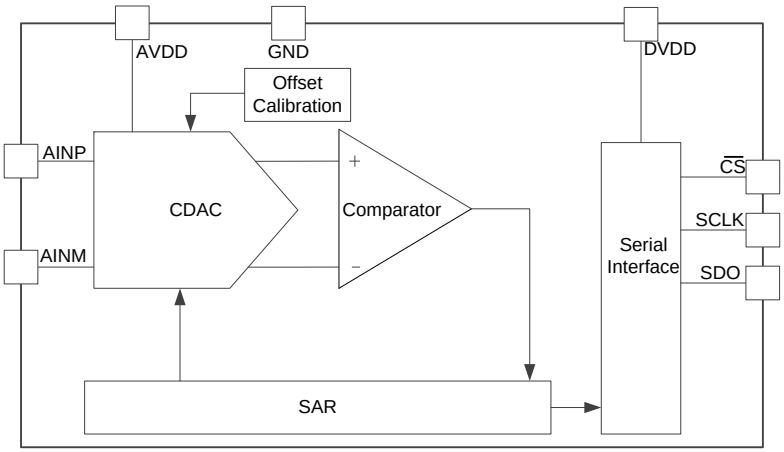
8.1 Overview

The ADS7043 is an ultralow-power, ultra-small analog-to-digital converter (ADC) that supports a wide analog input range. The analog input range for the device is defined by the AVDD supply voltage. The device samples the input voltage across the AINP and AINM pins on the $\overline{CS}$ falling edge and starts the conversion. The clock provided on the SCLK pin is used for conversion and data transfer. During conversions, both the AINP and AINM pins are disconnected from the sampling circuit. After the conversion completes, the sampling capacitors are reconnected across the AINP and AINM pins and the device enters acquisition phase.

The device has an internal offset calibration. The offset calibration can be initiated by the user either on power-up or during normal operation; see the *Offset Calibration* section for more details.

The device also provides a simple serial interface to the host controller and operates over a wide range of digital power supplies. The device requires only a 16-MHz SCLK for supporting a throughput of 1 MSPS. The digital interface also complies with the JESD8-7A (normal range) standard. The *Functional Block Diagram* section provides a block diagram of the device.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Reference

The device uses the analog supply voltage (AVDD) as a reference, as shown in Figure 32. TI recommends decoupling the AVDD pin with a 1-µF, low equivalent series resistance (ESR) ceramic capacitor. The minimum capacitor value required for AVDD is 200 nF. The AVDD pin functions as a switched capacitor load to the source powering AVDD. The decoupling capacitor provides the instantaneous charge required by the internal circuit and helps in maintaining a stable dc voltage on the AVDD pin. TI recommends powering the AVDD pin with a low output impedance and low-noise regulator (such as the TPS79101).

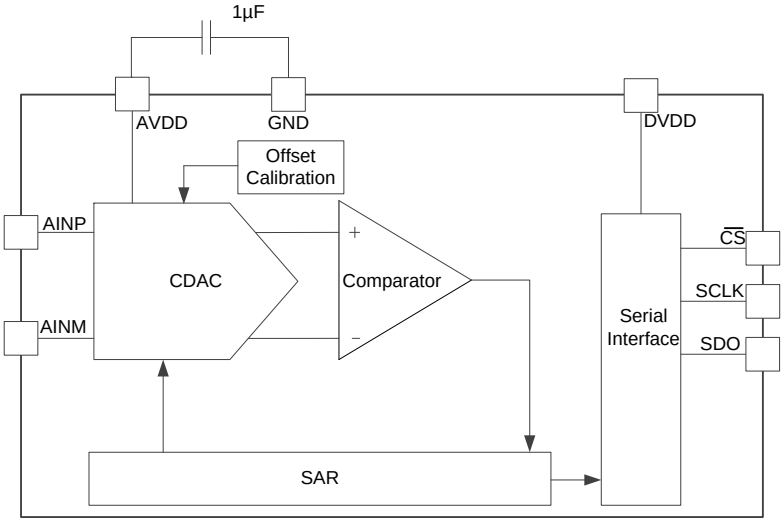


Figure 32. Reference for the Device

Feature Description (continued)

8.3.2 Analog Input

The device supports pseudo-differential analog inputs. The ADC samples the difference between AINP and AINM and converts for this voltage. The device is capable of accepting a signal from AVDD / 2 – 100 mV to AVDD / 2 + 100 mV on the AINM input and a signal from 0 V to AVDD on the AINP input. Figure 33 represents the equivalent analog input circuits for the sampling stage. The device has a low-pass filter followed by the sampling switch and sampling capacitor. The sampling switch is represented by an R_S (typically 50 Ω) resistor in series with an ideal switch and C_S (typically 15 pF) is the sampling capacitor. The ESD diodes are connected from both analog inputs to AVDD and ground.

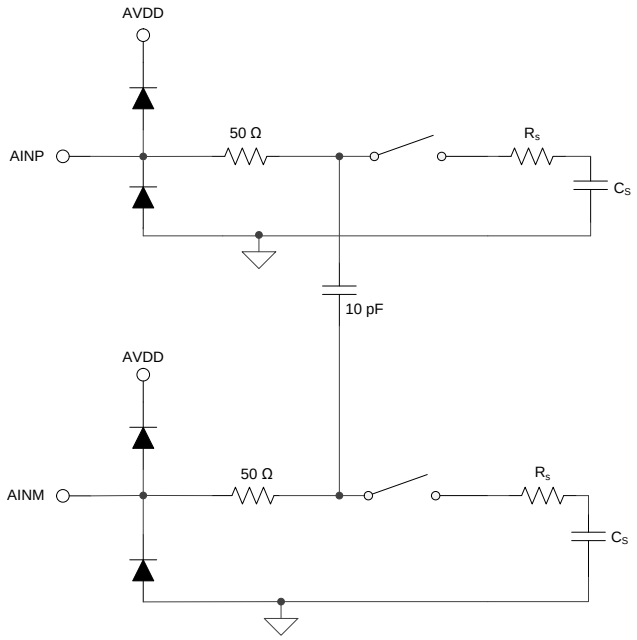


Figure 33. Equivalent Input Circuit for the Sampling Stage

The analog input full-scale range (FSR) is defined by the reference voltage of the ADC. The relationship between the FSR and the reference voltage can be determined by: FSR = V_{REF} = AVDD.

8.3.3 ADC Transfer Function

The device output is in straight binary format. The device resolution can be computed by Equation 1:

$$1 \text{ LSB} = \text{FSR} / 2^N \quad (1)$$

where:

- FSR = V_{REF} = AVDD and
- N = 12

Feature Description (continued)

Figure 34 and Table 1 show the ideal transfer characteristics for the device.

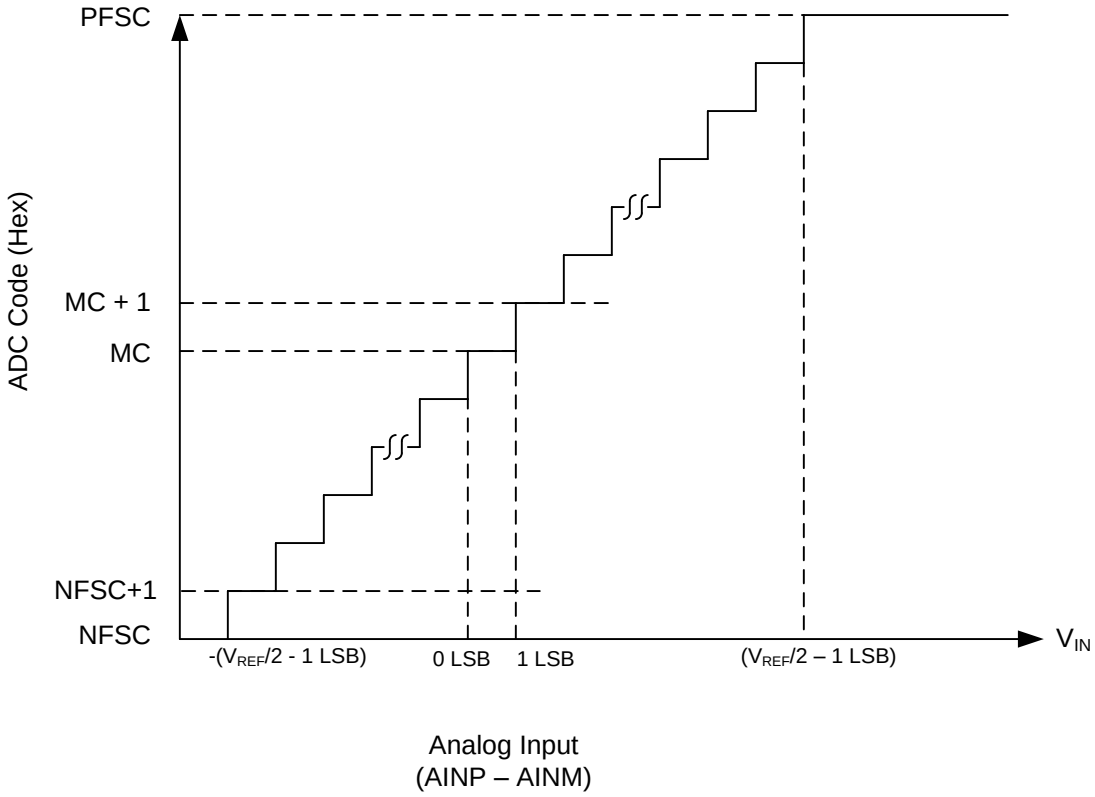


Figure 34. Ideal Transfer Characteristics

Table 1. Transfer Characteristics

INPUT VOLTAGE (AINP-AINM)	CODE	DESCRIPTION	IDEAL OUTPUT CODE
≤ –(V_{REF} / 2 – 1 LSB)	NFSC	Negative full-scale code	000
–(V_{REF} / 2 – 1 LSB) to –(V_{REF} / 2 – 2 LSBs)	NFSC + 1	—	001
0 to 1 LSB	MC	Mid code	800
1 LSB to 2 LSBs	MC + 1	—	801
≥ V_{REF} / 2 – 1 LSB	PFSC	Positive full-scale code	FFF

8.3.4 Serial Interface

The device supports a simple, SPI-compatible interface to the external host. The $\overline{CS}$ signal defines one conversion and serial transfer frame. A frame starts with a $\overline{CS}$ falling edge and ends with a $\overline{CS}$ rising edge. The SDO pin outputs the ADC conversion results. Figure 35 shows a detailed timing diagram for the serial interface. A minimum delay of t_{SU_CSCK} must elapse between the $\overline{CS}$ falling edge and the first SCLK falling edge. The device uses the clock provided on the SCLK pin for conversion and data transfer. The conversion result is available on the SDO pin with the first two bits set to 0, followed by 12 bits of the conversion result. The first zero is launched on the SDO pin on the $\overline{CS}$ falling edge. Subsequent bits (starting with another 0 followed by the conversion result) are launched on the SDO pin on subsequent SCLK falling edges. The SDO output remains low after 14 SCLKs. A $\overline{CS}$ rising edge ends the frame and brings the serial data bus to 3-state. For the acquisition of the next sample, a minimum time of t_{ACQ} must be provided after the conversion of the current sample is completed. For details on timing specifications, see the *Timing Characteristics* table.

The device initiates offset calibration on first $\overline{CS}$ falling edge after power-up and the SDO output remains low during the first serial transfer frame after power-up. For details, refer to the *Offset Calibration* section.

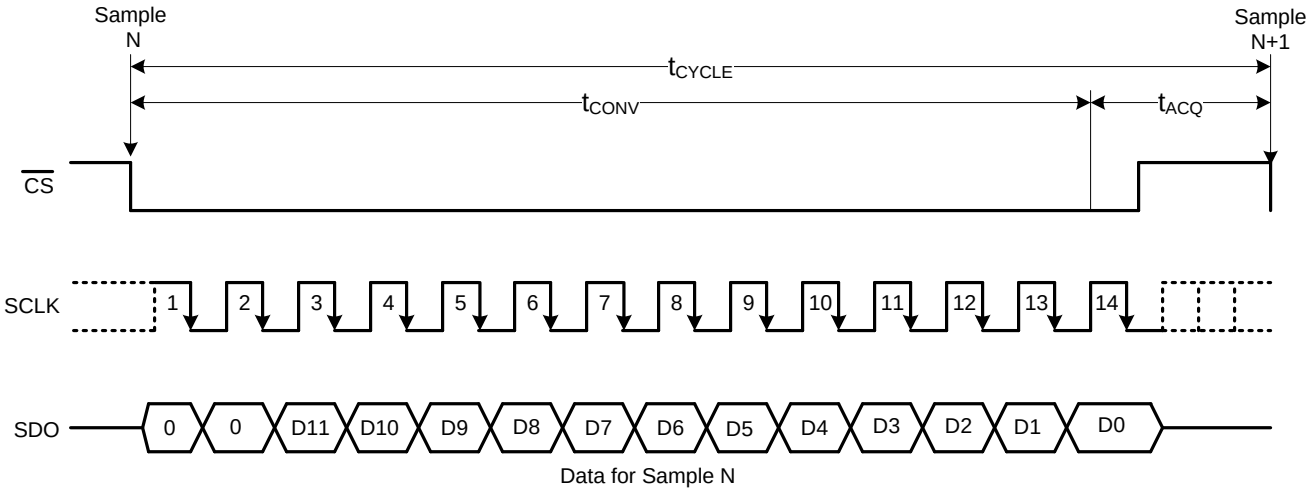


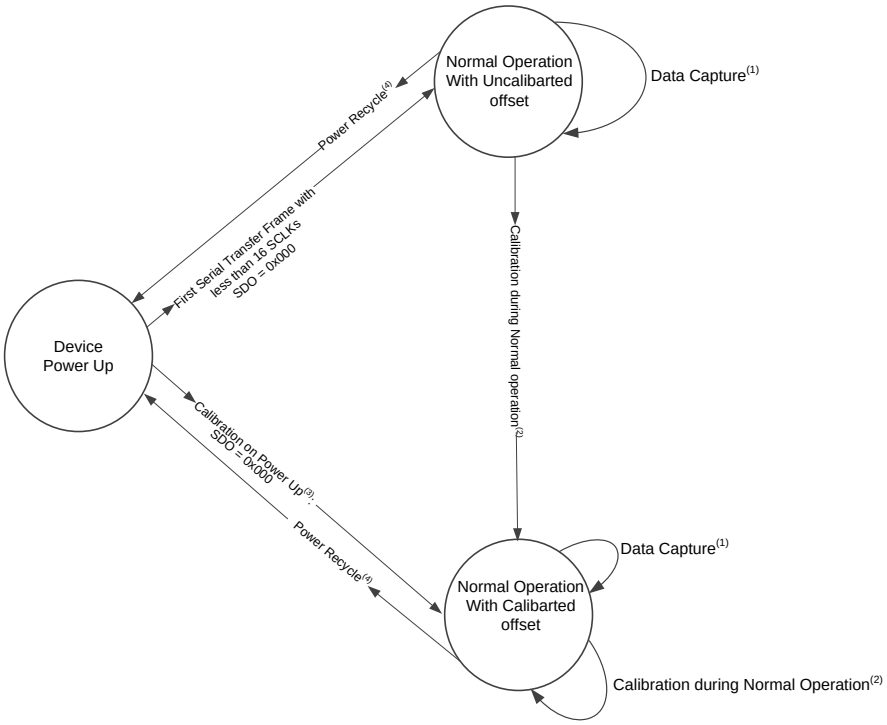
Figure 35. Serial Interface Timing Diagram

8.4 Device Functional Modes

8.4.1 Offset Calibration

The device includes a feature to calibrate its internal offset. The device initiates offset calibration on the first $\overline{CS}$ falling edge after power up and during offset calibration, the analog input pins (AINP and AINM) are disconnected from the sampling stage. After the first serial transfer frame, the device starts operating with either uncalibrated or calibrated offset, depending on the number of SCLKs provided in the first serial transfer frame. Offset calibration can also be initiated by the user during normal operation. Figure 36 shows the offset calibration process. The SDO output remains low during the first serial transfer frame.

The device includes an internal offset calibration register (OCR) that stores the offset calibration result. The OCR is an internal register and cannot be accessed by the user through the serial interface. The OCR is reset to zero on power-up. Therefore, TI recommends calibrating the offset on power-up to bring the offset within the specified limits. If there is a significant change in operating temperature or analog supply voltage, the offset can be recalibrated during normal operation.



(1) See the *Timing Characteristics* section for timing specifications.

(2) See the *Offset Calibration During Normal Operation* section for details.

(3) See the *Offset Calibration on Power-Up* section for details.

(4) The power recycle on the AVDD supply is required to reset the offset calibration and to bring the device to a power-up state.

Figure 36. Offset Calibration

Device Functional Modes (continued)

8.4.1.1 Offset Calibration on Power-Up

The device starts offset calibration on the first $\overline{CS}$ falling edge after power-up and calibration completes if the $\overline{CS}$ pin remains low for at least 16 SCLKs after the first $\overline{CS}$ falling edge. The SDO output remains low during calibration. The minimum acquisition time must be provided after calibration for acquiring the first sample. If the device is not provided with at least 16 SCLKs during the first serial transfer frame after power-up, the OCR is not updated. Table 2 provides the timing parameters for offset calibration on power-up.

For subsequent samples, the device adjusts the conversion results with the value stored in the OCR. The conversion result adjusted with the value stored in OCR is provided by the device on the SDO output. Figure 37 shows the timing diagram for offset calibration on power-up.

Table 2. Offset Calibration on Power-Up

		MIN	TYP	MAX	UNIT
$f_{CLK-CAL}$	SCLK frequency for calibration at 2.25 V < AVDD < 3.6 V			16	MHz
$f_{CLK-CAL}$	SCLK frequency for calibration at 1.65 V < AVDD < 2.25 V			12	MHz
$t_{POWERUP-CAL}$	Calibration time at power-up	16 t_{SCLK}			ns
t_{ACQ}	Acquisition time	200			ns
t_{PH_CS}	$\overline{CS}$ high time	t_{ACQ}			ns

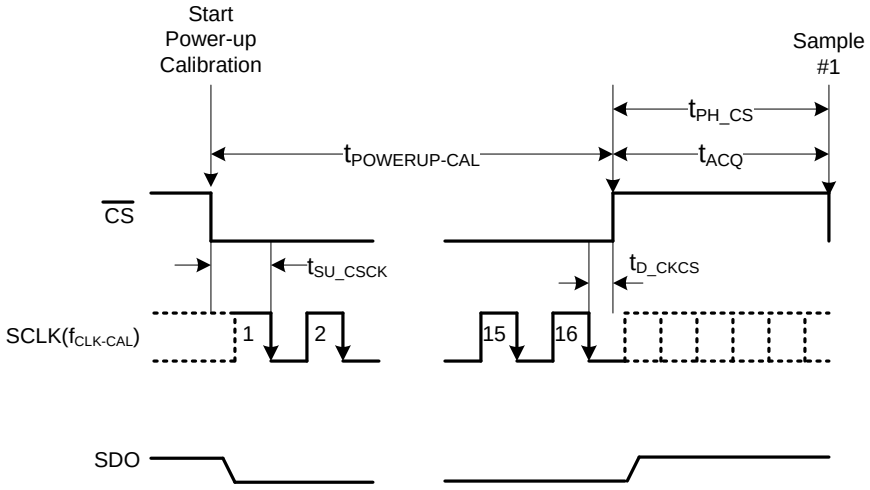


Figure 37. Offset Calibration on Power-Up Timing Diagram

8.4.1.2 Offset Calibration During Normal Operation

The offset can also be calibrated during normal device operation. Offset calibration can be done during normal device operation if at least 32 SCLKs are provided in one serial transfer frame. During the first 14 SCLKs, the device converts the sample acquired on the $\overline{CS}$ falling edge and provides data on the SDO output. The device initiates the offset calibration on the 17th SCLK falling edge and calibration is completed on the 32nd SCLK falling edge. The SDO output remains low after the 14th SCLK falling edge and SDO goes to 3-state after $\overline{CS}$ goes high. If the device is provided with less than 32 SCLKs during a serial transfer frame, the OCR is not updated. Table 3 provides the timing parameters for offset calibration during normal operation.

For subsequent samples, the device adjusts the conversion results with the value stored in OCR. The conversion result adjusted with the value stored in the OCR is provided by the device on the SDO output. Figure 38 shows the timing diagram for offset calibration during normal operation.

Table 3. Offset Calibration During Normal Operation

		MIN	TYP	MAX	UNIT
$f_{CLK-CAL}$	SCLK frequency for calibration for 2.25 V < AVDD < 3.6 V			16	MHz
$f_{CLK-CAL}$	SCLK frequency for calibration for 1.65 V < AVDD < 2.25 V			12	MHz
t_{CAL}	Calibration time during normal operation	16 t_{SCLK}			ns
t_{ACQ}	Acquisition time	200			ns
t_{PH_CS}	$\overline{CS}$ high time	t_{ACQ}			ns

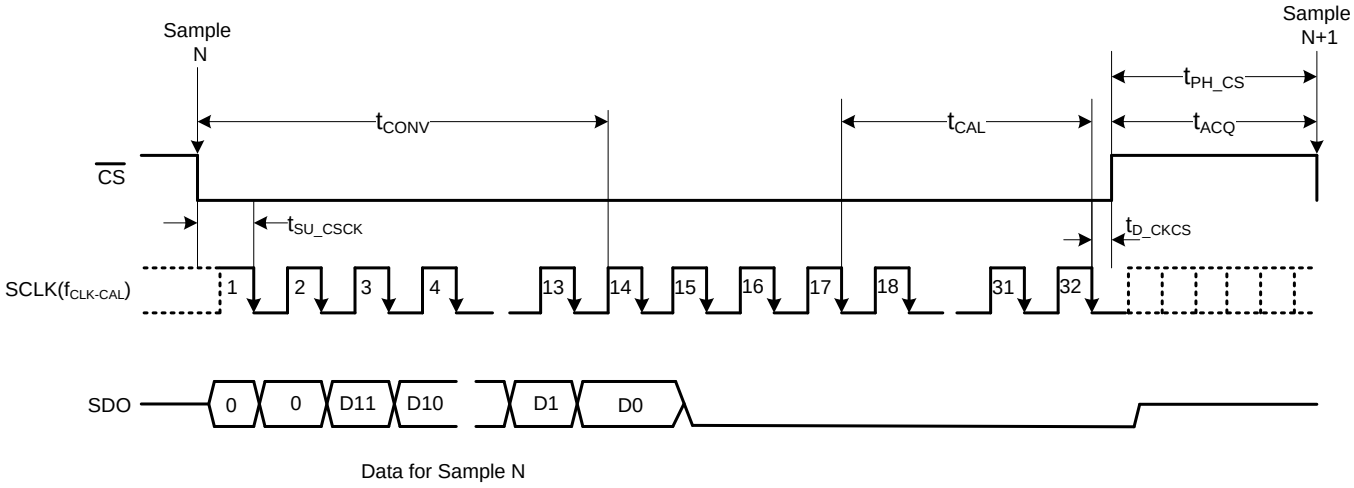


Figure 38. Offset Calibration During Normal Operation Timing Diagram

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The two primary circuits required to maximize the performance of a high-precision, successive approximation register (SAR), analog-to-digital converter (ADC) are the input driver and the reference driver circuits. This section details some general principles for designing the input driver circuit, reference driver circuit, and provides some application circuits designed for the ADS7043.

9.2 Typical Applications

9.2.1 Single-Supply DAQ with the ADS7043

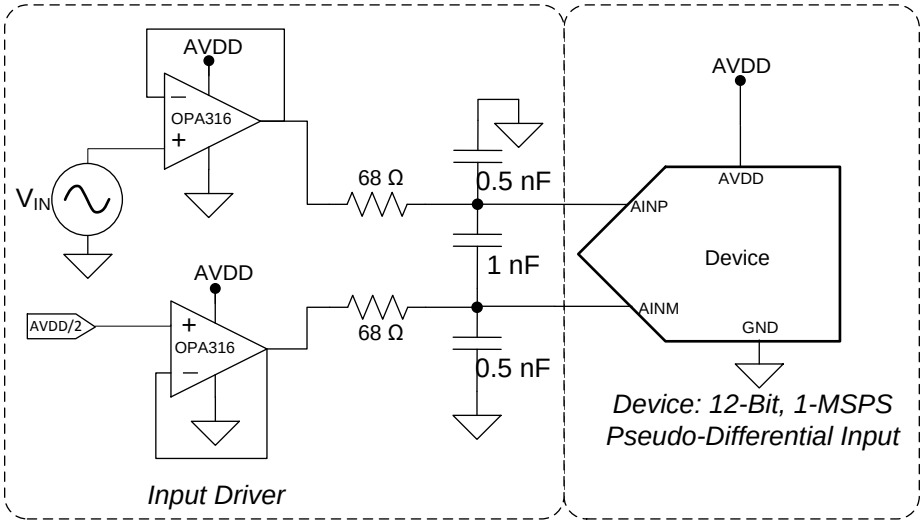


Figure 39. DAQ Circuit: Single-Supply DAQ

9.2.1.1 Design Requirements

The goal of this application is to design a single-supply digital acquisition (DAQ) circuit based on the ADS7043 with SNR greater than 69 dB and THD less than –80 dB for a input signal having an amplitude of AVDD / 2 with a common-mode voltage of AVDD / 2 and input frequencies of 2 kHz at a throughput of 1 MSPS.

9.2.1.2 Detailed Design Procedure

The input driver circuit for a high-precision ADC mainly consists of two parts: a driving amplifier and an antialiasing filter. Careful design of the front-end circuit is critical to meet the linearity and noise performance of a high-precision ADC.

Typical Applications (continued)

9.2.1.2.1 Antialiasing Filter

Converting analog-to-digital signals requires sampling an input signal at a rate greater than or equal to the Nyquist rate. Any higher frequency content in the input signal beyond half the sampling frequency is digitized and folded back into the low-frequency spectrum. This process is called *aliasing*. Therefore, an external, antialiasing filter must be used to remove the harmonic content from the input signal before being sampled by the ADC. An antialiasing filter is designed as a low-pass RC filter, for which the 3-dB bandwidth is optimized for noise, response time, and throughput. For dc signals with fast transients (including multiplexed input signals), a high-bandwidth filter is designed to allow the signal to be accurately set at the ADC inputs during the small acquisition time window. Figure 40 provides the equation for determining the bandwidth of antialiasing filter.

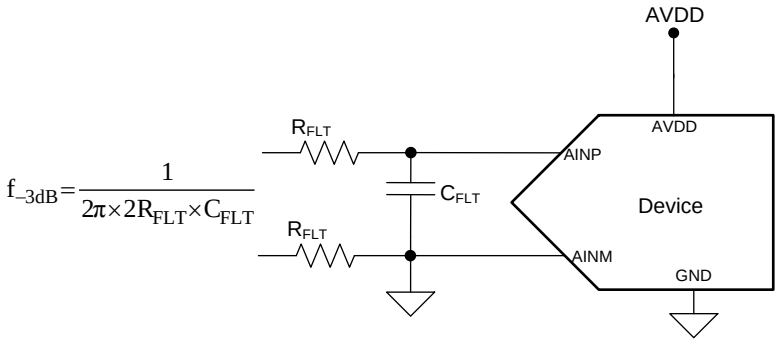


Figure 40. Antialiasing Filter

For ac signals, the filter bandwidth must be kept low to band limit the noise fed into the ADC input, thereby increasing the signal-to-noise ratio (SNR) of the system. Besides filtering the noise from the front-end drive circuitry, the RC filter also helps attenuate the sampling charge injection from the switched-capacitor input stage of the ADC. A filter capacitor, C_{FLT}, is connected across the ADC inputs. This capacitor helps reduce the sampling charge injection and provides a charge bucket to quickly charge the internal sample-and-hold capacitors during the acquisition process. As a rule of thumb, the value of this capacitor must be at least 20 times the specified value of the ADC sampling capacitance. For this device, the input sampling capacitance is equal to 15 pF. Thus, the value of C_{FLT} must be greater than 300 pF. The capacitor must be a COG- or NPO-type because these capacitor types have a high-Q, low-temperature coefficient, and stable electrical characteristics under varying voltages, frequency, and time.

Note that driving capacitive loads can degrade the phase margin of the input amplifiers, thus making the amplifier marginally unstable. To avoid amplifier stability issues, series isolation resistors (R_{FLT}) are used at the output of the amplifiers. A higher value of R_{FLT} is helpful from the amplifier stability perspective, but adds distortion as a result of interactions with the nonlinear input impedance of the ADC. Distortion increases with source impedance, input signal frequency, and input signal amplitude. Therefore, the selection of R_{FLT} requires balancing the stability and distortion of the design.

The input amplifier bandwidth must be much higher than the cutoff frequency of the antialiasing filter. TI strongly recommends performing a SPICE simulation to confirm that the amplifier has more than 40° phase margin with the selected filter. Simulation is critical because even with high-bandwidth amplifiers, some amplifiers may require more bandwidth than others to drive similar filters.

Typical Applications (continued)

9.2.1.2.2 Input Amplifier Selection

Selection criteria for the input amplifiers is highly dependent on the input signal type and the performance goals of the data acquisition system. Some key amplifier specifications to consider while selecting an appropriate amplifier to drive the inputs of the ADC are:

- Small-signal bandwidth: Select the small-signal bandwidth of the input amplifiers to be high enough to settle the input signal in the acquisition time of the ADC. Higher bandwidth reduces the closed-loop output impedance of the amplifier, thus allowing the amplifier to more easily drive the low cutoff frequency RC filter at the ADC inputs. Higher bandwidth also minimizes the harmonic distortion at higher input frequencies. In order to maintain the overall stability of the input driver circuit, select the amplifier bandwidth as described in Equation 2:

$$GBW \geq 4 \times \frac{1}{2\pi \times 2R_{FLT} \times C_{FLT}} \quad (2)$$

  where:
  - GBW = Unity-gain bandwidth

- Noise: Noise contribution of the front-end amplifiers must be low enough to prevent any degradation in SNR performance of the system. As a rule of thumb, to ensure that the noise performance of the data acquisition system is not limited by the front-end circuit, keep the total noise contribution from the front-end circuit below 20% of the input-referred noise of the ADC. Noise from the input driver circuit is band limited by designing a low cutoff frequency RC filter, as explained in Equation 3.

$$N_G \times \sqrt{2} \times \sqrt{\left(\frac{V_{1/f\_AMP\_PP}}{6.6}\right)^2 + e^2_{n\_RMS} \times \frac{\pi}{2} \times f_{-3dB}} \leq \frac{1}{5} \times \frac{V_{REF}}{2\sqrt{2}} \times 10^{-\left(\frac{SNR(dB)}{20}\right)} \quad (3)$$

  where:
  - V_{1/f_AMP_PP} is the peak-to-peak flicker noise in µVrms,
  - e_{n_RMS} is the amplifier broadband noise,
  - f_{-3dB} is the –3-dB bandwidth of the RC filter, and
  - N_G is the noise gain of the front-end circuit.

- Settling time: For dc signals with fast transients that are common in a multiplexed application, the input signal must settle to the desired accuracy at the inputs of the ADC during the acquisition time window. This condition is critical to maintain the overall linearity performance of the ADC. Typically, the amplifier data sheets specify the output settling performance only up to 0.1% to 0.001%, which may not be sufficient for the desired accuracy. Therefore, always verify the settling behavior of the input driver with TINA™-SPICE simulations before selecting the amplifier.

The OPA316 is selected for this application for its rail-to-rail input and output swing, low-noise (11 nV/√Hz), and low-power (400 µA) performance to support a single-supply data acquisition circuit.

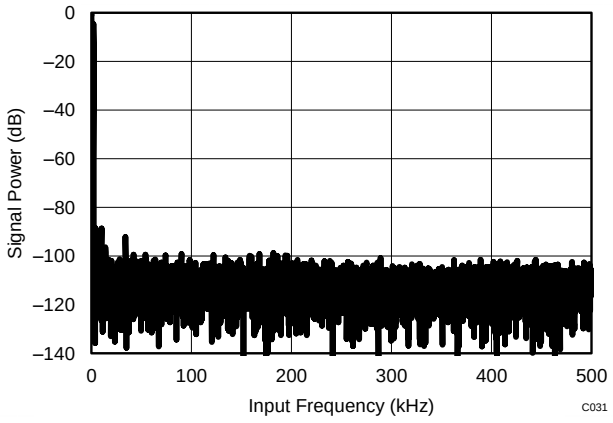
9.2.1.2.3 Reference Circuit

The analog supply voltage of the device is also used as a voltage reference for conversion. TI recommends decoupling the AVDD pin with a 1-µF, low-ESR ceramic capacitor. The minimum capacitor value required for AVDD is 200 nF.

TI Precision Designs	For a step-by-step design procedure, circuit schematics, bill of materials, PCB files, simulation results, and test results, refer to TI Precision Design TIPD168, *Three 12-Bit Data Acquisition Reference Designs Optimized for Low Power and Ultra-Small Form Factor* (TIDU390).

9.2.1.3 Application Curve

Figure 41 shows the FFT plot for the device with a 2-kHz input frequency for the circuit in Figure 39.



SNR = 70.4 dB THD = –79.5 dB SINAD = 69.9 dB

Number of samples = 8192

Figure 41. Test Results for the ADS7043 and OPA316 for a 2-kHz Input

9.2.2 DAQ Circuit with the ADS7043 for Maximum SINAD at a 250-kHz f_{IN}

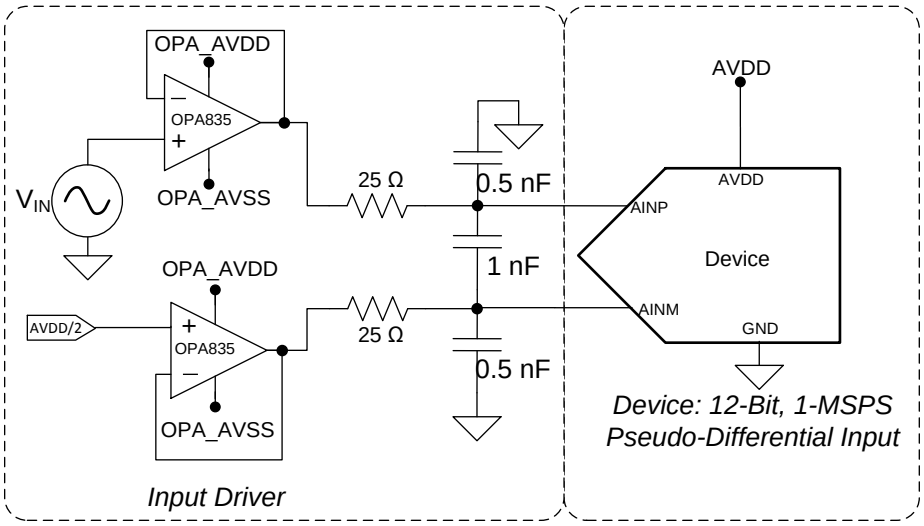


Figure 42. ADS7043 DAQ Circuit for Maximum SINAD

9.2.2.1 Design Requirements

The goal of this application is to design a data acquisition (DAQ) circuit based on the ADS7043 with SINAD greater than 68 dB for input signals having an amplitude of AVDD / 2 with common-mode voltage of AVDD / 2 and input frequencies up to 250 kHz.

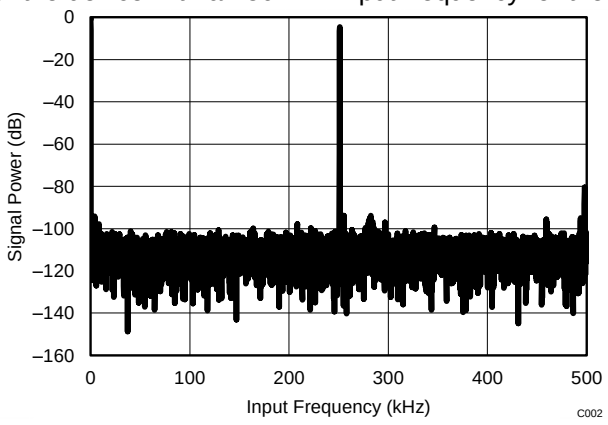
9.2.2.2 Detailed Design Procedure

See the *Detailed Design Procedure* section in the *Single-Supply DAQ with the ADS7043* application for further details.

To achieve a SINAD of 68 dB, the operational amplifier must have high bandwidth to settle the input signal within the acquisition time of the ADC. The operational amplifier must have low noise to keep the total system noise below 20% of the input-referred noise of the ADC. For the application circuit shown in Figure 42, the OPA835 is selected for its high-bandwidth (56 MHz) and low-noise (9.3 nV/√Hz) performance.

9.2.2.3 Application Curve

Figure 43 shows the FFT plot for the device with a 250-kHz input frequency for the circuit shown in Figure 42.



SNR = 69.7 dB THD = –75.5 dB SINAD = 68.7 dB

Number of samples = 8192

Figure 43. Test Results for the ADS7043 and OPA835 for a 250-kHz Input

10 Power-Supply Recommendations

10.1 AVDD and DVDD Supply Recommendations

The device has two separate power supplies: AVDD and DVDD. The device operates on AVDD; DVDD is used for the interface circuits. AVDD and DVDD can be independently set to any value within the permissible ranges. The AVDD supply also defines the full-scale input range of the device. Decouple the AVDD and DVDD pins individually with 1-µF ceramic decoupling capacitors, as shown in Figure 44. The minimum capacitor value required for AVDD and DVDD is 200 nF and 20 nF, respectively. If both supplies are powered from the same source, a minimum capacitor value of 220 nF is required for decoupling.

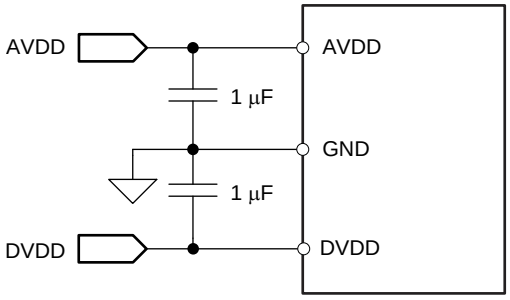


Figure 44. Power-Supply Decoupling

10.2 Estimating Digital Power Consumption

The current consumption from the DVDD supply depends on the DVDD voltage, load capacitance on the SDO line, and the output code. The load capacitance on the SDO line is charged by the current from the SDO pin on every rising edge of the data output and is discharged on every falling edge of the data output. The current consumed by the device from the DVDD supply can be calculated by Equation 4:

$$I_{DVDD} = C \times V \times f \quad (4)$$

where:

- C = Load capacitance on the SDO line,
- V = DVDD supply voltage, and
- f = Number of transitions on the SDO output.

The number of transitions on the SDO output depends on the output code, and thus changes with the analog input. The maximum value of f occurs when data output on the SDO change on every SCLK. SDO changing on every SCLK results in an output code of AAAh or 555h. For an output code of AAAh or 555h at a 1-MSPS throughput, the frequency of transitions on the SDO output is 6 MHz.

To keep the current consumption at the lowest possible value, the DVDD supply must be kept at the lowest permissible value and the capacitance on the SDO line must be kept as low as possible.

10.3 Optimizing Power Consumed by the Device

- Keep the analog supply voltage (AVDD) as per the analog input full-scale range (FSR) requirement.
- Keep the digital supply voltage (DVDD) at the lowest permissible value.
- Reduce the load capacitance on the SDO output.
- Run the device at optimum throughput. Power consumption reduces with throughput.

11 Layout

11.1 Layout Guidelines

Figure 45 shows a board layout example for the ADS7043. Use a ground plane underneath the device and partition the PCB into analog and digital sections. Avoid crossing digital lines with the analog signal path and keep the analog input signals and the reference input signals away from noise sources. In Figure 45, the analog input and reference signals are routed on the top and left side of the device while the digital connections are routed on the bottom and right side of the device.

The power sources to the device must be clean and well-bypassed. Use 1-µF ceramic bypass capacitors in close proximity to the analog (AVDD) and digital (DVDD) power-supply pins. Avoid placing vias between the AVDD and DVDD pins and the bypass capacitors. Connect all ground pins to the ground plane using short, low-impedance paths. The AVDD supply voltage for the ADS7043 also functions as a reference for the device. Place the decoupling capacitor (C_{REF}) for AVDD close to the device AVDD and GND pins. C_{REF} must be connected to the device pins with thick copper tracks, as shown in Figure 45.

The fly-wheel RC filters are placed close to the device. Among ceramic surface-mount capacitors, COG (NPO) ceramic capacitors provide the best capacitance precision. The type of dielectric used in COG (NPO) ceramic capacitors provides the most stable electrical properties over voltage, frequency, and temperature changes.

11.2 Layout Example

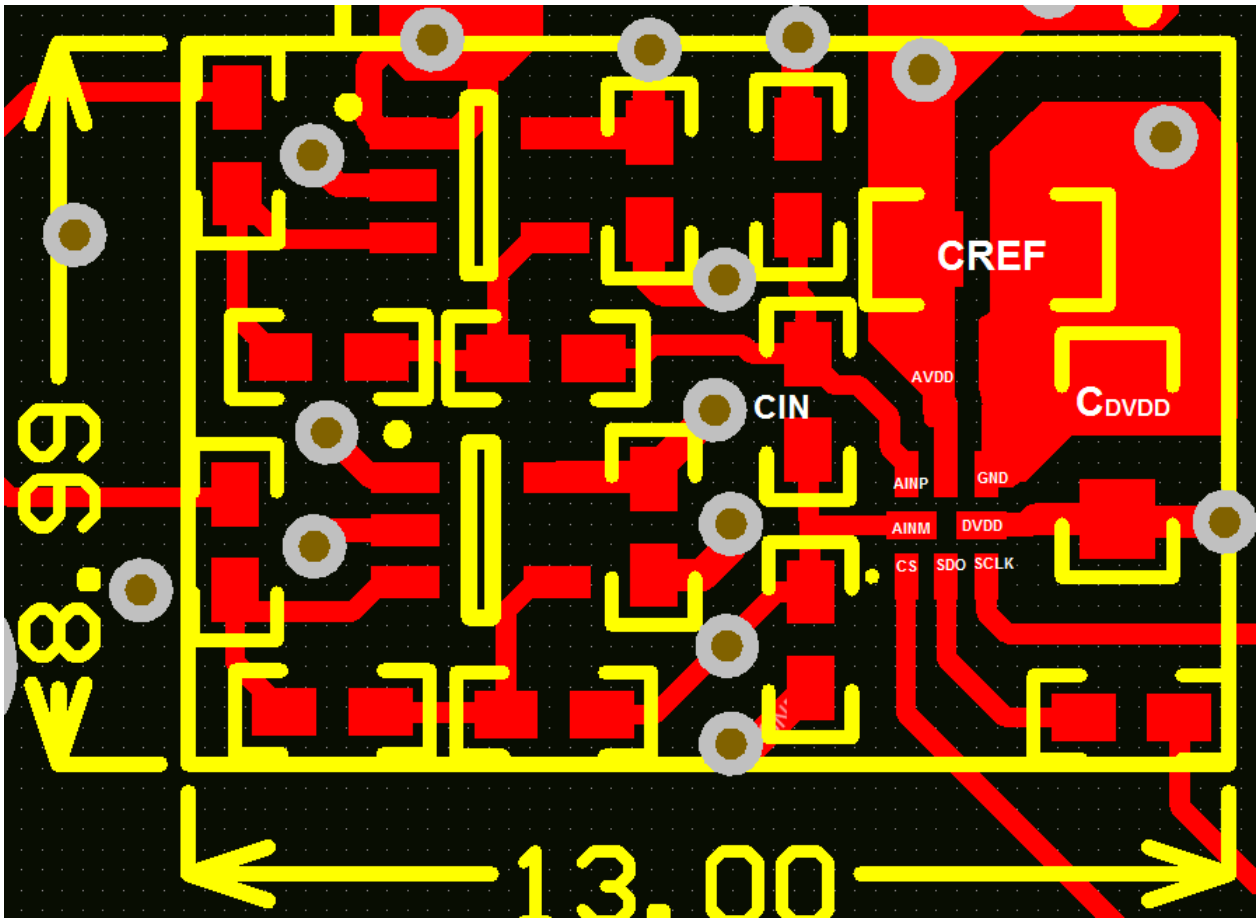


Figure 45. Example Layout

12 器件和文档支持

12.1 文档支持

12.1.1 相关文档

相关文档如下：

- 《OPA316 数据表》（文献编号 SBOS703）
- 《OPA835 数据表》（文献编号 SLOS713）
- 《THS4531A 数据表》（文献编号 SLOS823）
- 《TPS79101 数据表》（文献编号 SLVS325）
- 《全差动放大器分析》（文献编号 SLYT157）

12.2 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community ***TI's Engineer-to-Engineer (E2E) Community.*** Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

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串行外设接口 (SPI) is a trademark of Motorola.
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12.4 静电放电警告

ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。 精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

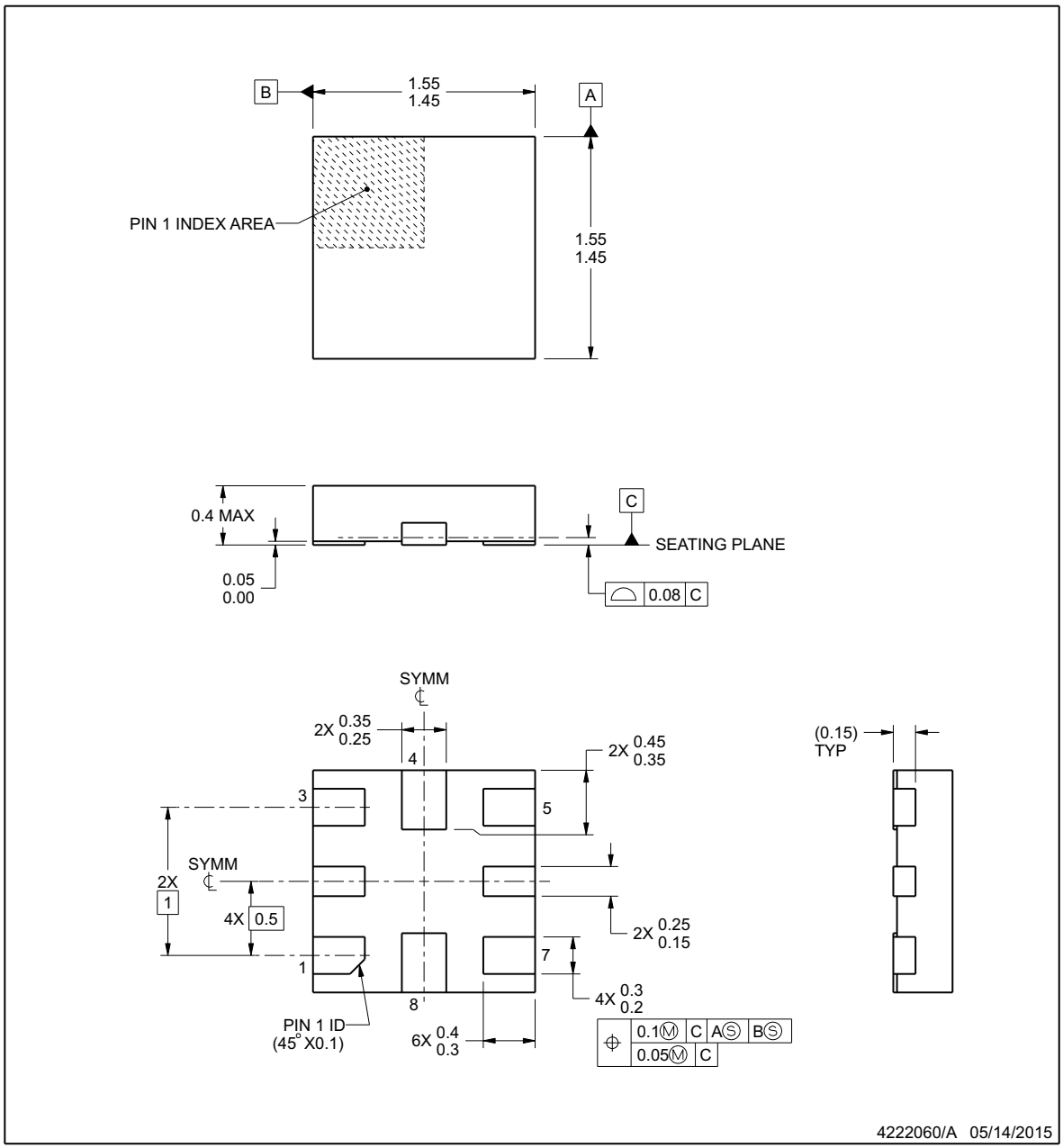
以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGE OUTLINE

RUG0008A

X2QFN - 0.4 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



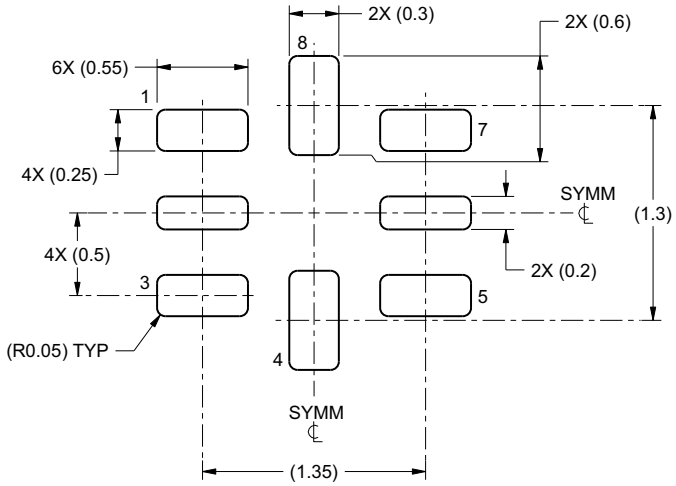
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

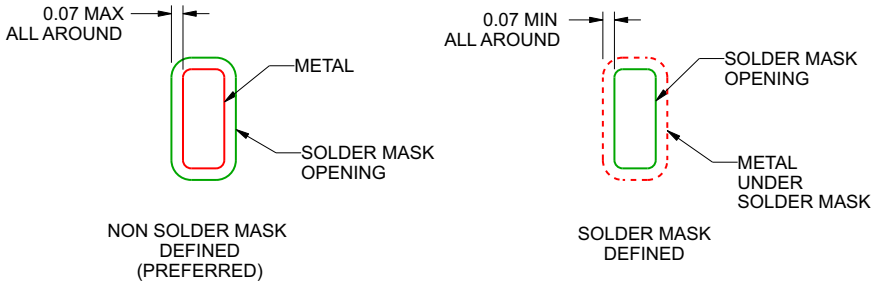
EXAMPLE BOARD LAYOUT

RUG0008A — **X2QFN - 0.4 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
SCALE:25X



SOLDER MASK DETAILS
NOT TO SCALE

4222060/A 05/14/2015

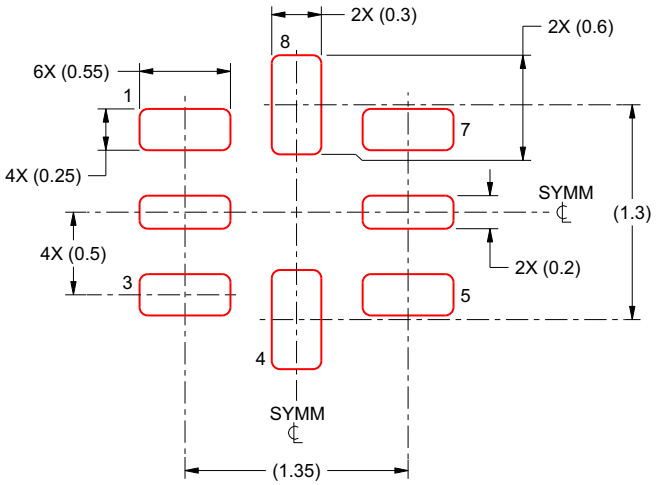
NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

EXAMPLE STENCIL DESIGN

RUG0008A — **X2QFN - 0.4 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICKNESS
SCALE:25X

4222060/A 05/14/2015

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
ADS7043IDCUR	Active	Production	VSSOP (DCU) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7043
ADS7043IDCUR.A	Active	Production	VSSOP (DCU) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7043
ADS7043IDCUT	Active	Production	VSSOP (DCU) | 8	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7043
ADS7043IDCUT.A	Active	Production	VSSOP (DCU) | 8	250 | SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7043
ADS7043IRUGR	Active	Production	X2QFN (RUG) | 8	3000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	FW
ADS7043IRUGR.A	Active	Production	X2QFN (RUG) | 8	3000 | LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	FW

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

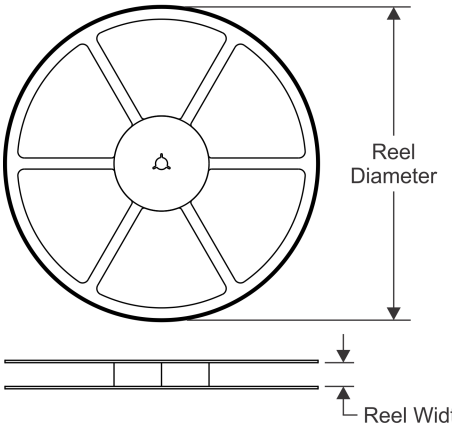
(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

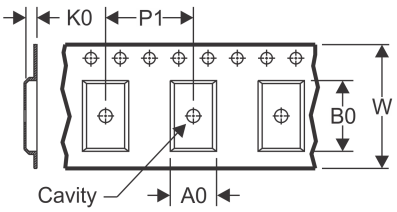
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

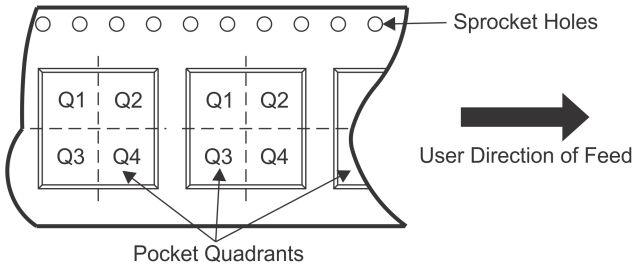


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

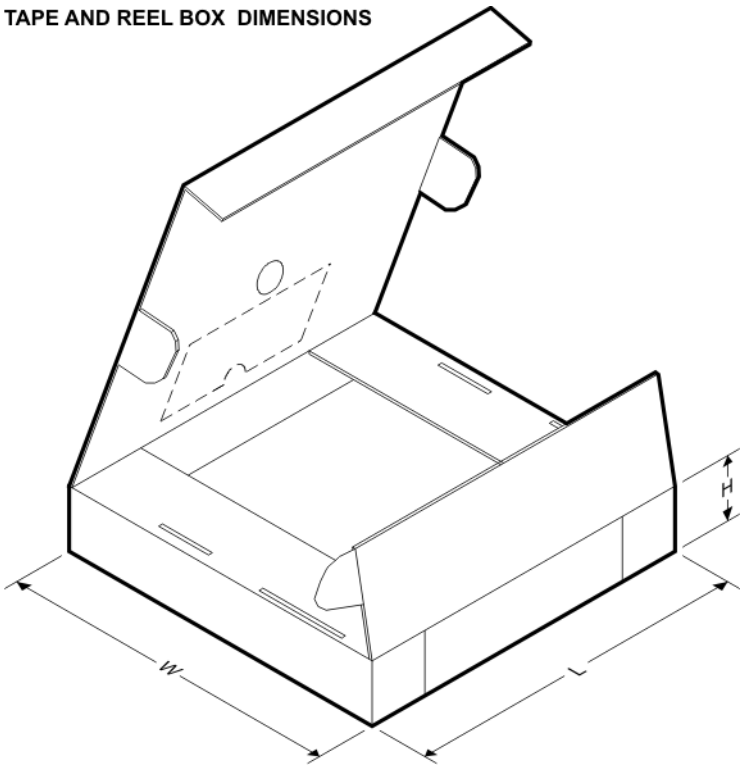
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS7043IDCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
ADS7043IDCUT	VSSOP	DCU	8	250	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
ADS7043IRUGR	X2QFN	RUG	8	3000	180.0	8.4	1.6	1.6	0.66	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

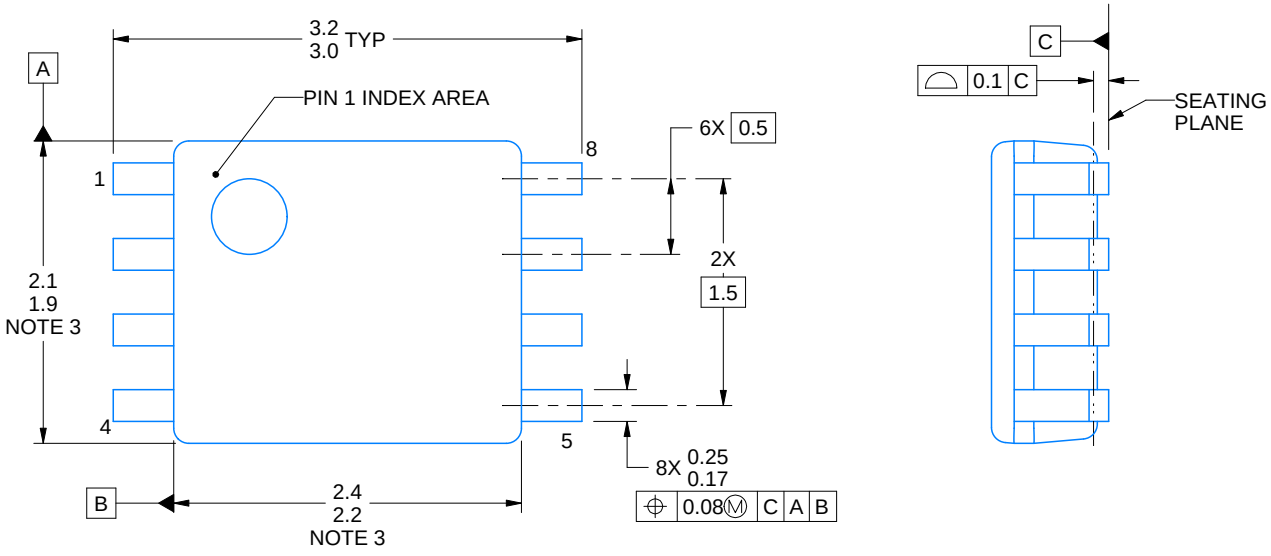
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADS7043IDCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
ADS7043IDCUT	VSSOP	DCU	8	250	202.0	201.0	28.0
ADS7043IRUGR	X2QFN	RUG	8	3000	202.0	201.0	28.0

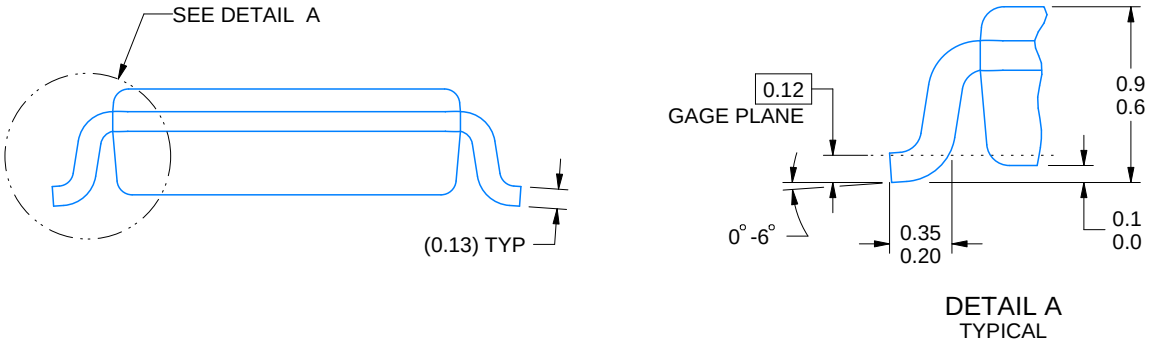
DCU0008A

PACKAGE OUTLINE

VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE

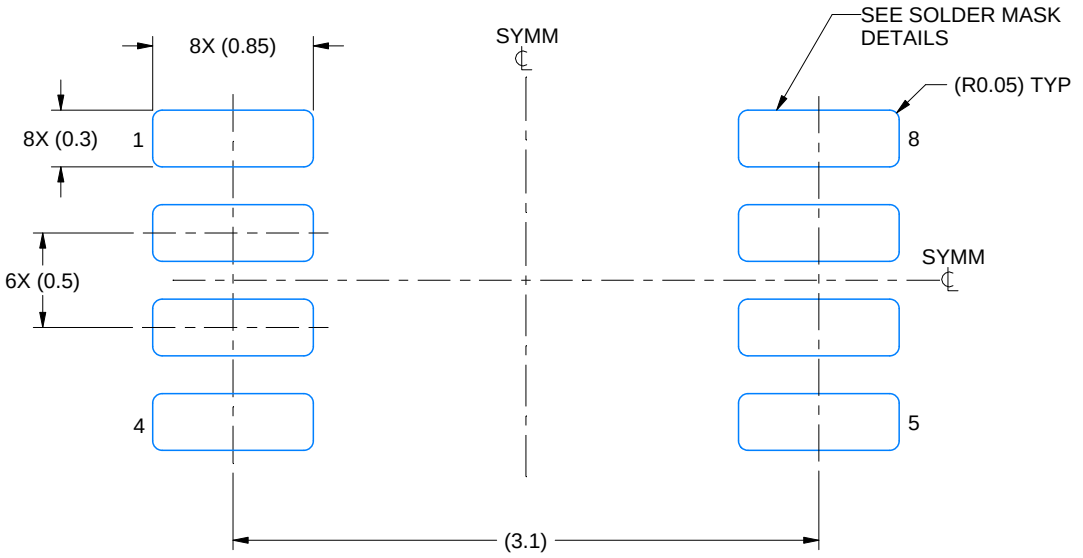




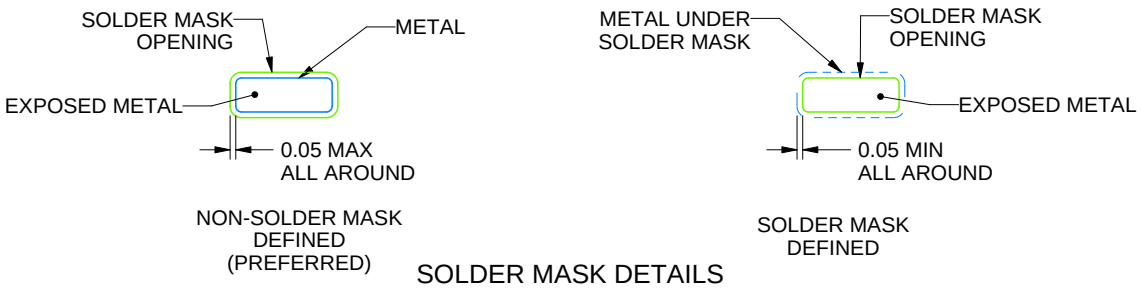
4225266/A 09/2014

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-187 variation CA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 25X

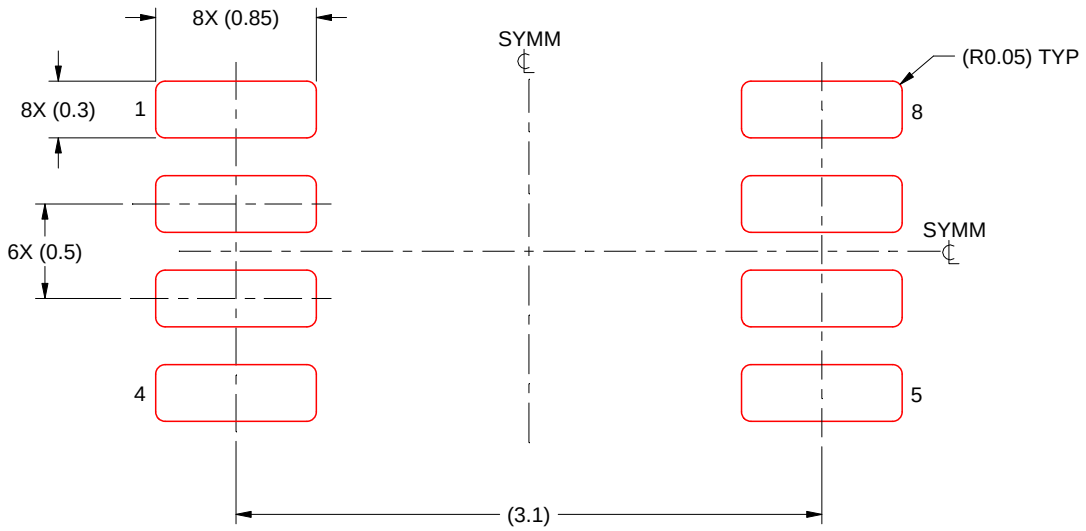


SOLDER MASK DETAILS

4225266/A 09/2014

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 25X

4225266/A 09/2014

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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